Experiment-5

Aim:

To implement a common source amplifier using diode connected load of gain 5 and analyse its transient and ac characteristics.

Tool Used:

LTspice

Theory:

When the input signal is applied at the gate terminal and source terminal, then the output voltage is amplified and obtained across the resistor at the load in the drain terminal. This is called a common source amplifier.

Common source amplifier is similar to the common-emitter follower of Bipolar Junction transistor. If we use P-channel FET, the polarity of the input voltage will be reversed.

For a Level 3 NMOS let's assume

VDD = 1.8V

VT = 0.4V

VGS = 0.6V

 $Kn = 120 \mu A/V^2$,

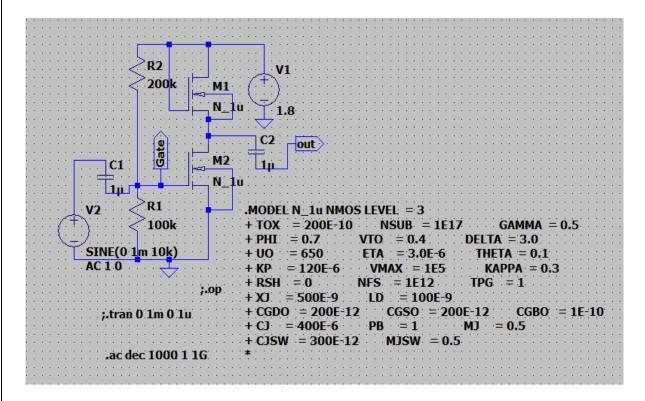
Which gives a value of (W/L) = (25) for 1mA ID.

Also, for these values' gm is attained as $10m\Omega$ -1, therefore for gain 10, RD is taken as $1K\Omega$.

The value of VDS should be maintained above (VGS - VT = 0.6 - 0.4 = 0.2V) for the transistor to stay in saturation region.

As for M2, the width is taken as $250\mu m$ and the length is taken as $10\mu m$ and for M1, the width is taken as $50\mu m$ and the length is taken as $50\mu m$.

Circuit Schematic: [Level 3]



DC Operating Point

* C:\Users\singh\Documents\Analog IC Design Lab\Lab4\common gat

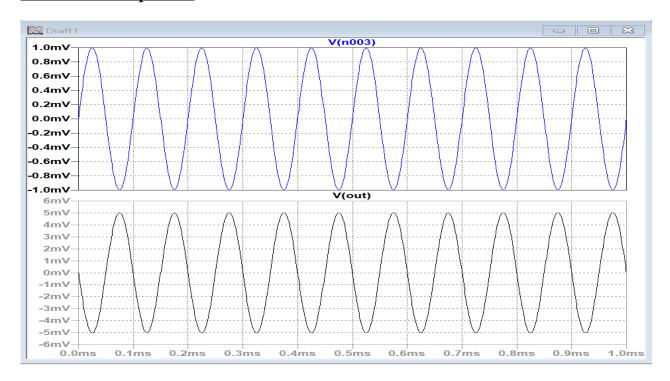
--- Operating Point ---

1.8

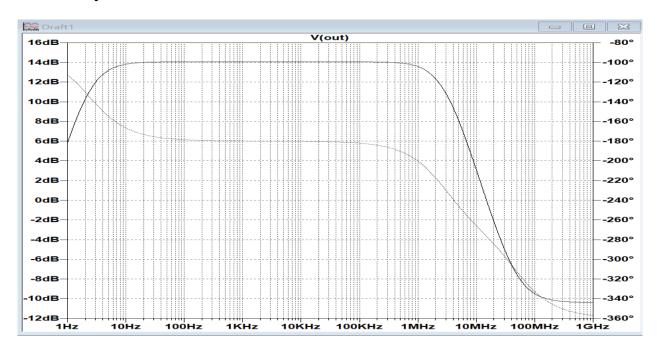
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V(n001):
                               voltage
V(n002):
                0.405172
                               voltage
                0.6
                               voltage
V(gate):
V(n003):
                               voltage
V(out):
                4.05171e-007
                               voltage
Id (M2):
                4.62144e-005
                               device current
Iq (M2):
                                device current
                -4.15172e-013
Ib (M2):
                               device current
                -4.62144e-005
                               device_current
Is (M2):
Id(M1):
                4.62144e-005
                                device current
Ig (M1):
                                device current
                -1.40483e-012
Ib (M1):
                               device current
                -4.62144e-005 device current
Is(M1):
                4.05171e-019
                                device current
I(C2):
                -6e-019
I(C1):
                                device current
I(R2):
                6e-006
                                device current
I(R1):
                6e-006
                               device current
                6e-019
I(V2):
                                device current
I(V1):
                -5.22144e-005 device current
```

Output Waveforms:

Transient Response:



AC Analysis:



Result:

The circuit is designed for a gain of 5 and the output is verified to be correct.

- Bandwidth is obtained to be: 3.17MHz
- Cutoff Freq: 3.17MHz, 2.36Hz